NARSIMHA REDDY ENGINEERING COLLEGE UGC AUTONOMOUS INSTITUTION

Maisammaguda (V), Kompally - 500100, Secunderabad, Telangana State, India

ELECTRONIC DEVICES AND CIRCUITS

B.Tech. I Year I Sem.

Course Objectives:

LTPC

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Permanently affiliated to JNTUH

UGC - Autonomous Institute

Approved by AICTE

Accredited by NBA & NAAC with 'A' Grade

- **1.** To study the characteristics of diodes.
- 2. To emphasis the semiconductor devices like diodes in real life.
- **3.** To acquire the knowledge of features of **BJT**.
- 4. To study and understand the characteristics of JFET and MOSFET.
- 5. To learn the characteristics of special purpose devices.

Course Outcomes: Upon completion of the Course, the students will be able to:

- 1. Acquire the knowledge of various electronic devices and their use on real life.
- 2. Know the applications of various devices.
- 3. Understand the characteristics of BJT.
- 4. Perceive the knowledge about JFET and MOSFET.
- 5. Acquire the knowledge about the role of special purpose devices and their applications.

Course	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12
CO1	3	1	2	-	-	1	1	-	-	-	-	1
CO2	3	2	3	-	-	2	1	-	-	-	-	1
CO3	3	3	3	-	-	2	1	-	-	-	-	1
CO4	3	3	3	-	-	2	1	-	-	-	-	1
CO5	3	3	3	-	-	2	1	-	-	-	-	1

UNIT - I

Diodes: Diode - Static and Dynamic resistances, Equivalent circuit, Diffusion and Transition Capacitances, V-I Characteristics, Diode as a switch- switching times.

UNIT - II

Diode Applications: Rectifier - Half Wave Rectifier, Full Wave Rectifier, Bridge Rectifier, Rectifiers with Capacitive and Inductive Filters, Clippers-Clipping at two independent levels, Clamper-Clamping Circuit Theorem, Clamping Operation, Types of Clampers.

UNIT - III

Bipolar Junction Transistor (BJT): Principle of Operation, Common Emitter, Common Base and Common Collector Configurations, Transistor as a switch, switching times,

UNIT - IV

Junction Field Effect Transistor (FET): Construction, Principle of Operation, Pinch-Off Voltage, Volt- Ampere Characteristic, Comparison of BJT and FET, FET as Voltage Variable Resistor, MOSFET, MOSTET as a capacitor.

UNIT – V

Special Purpose Devices: Zener Diode - Characteristics, Zener diode as Voltage Regulator, Principleof Operation - SCR, Tunnel diode, UJT, Varactor Diode, Photo diode, Solar cell, LED, Schottky diode.

TEXT BOOKS:

- 1. Jacob Millman Electronic Devices and Circuits, McGraw Hill Education
- 2. Robert L. Boylestead, Louis Nashelsky- Electronic Devices and Circuits

theory, 11th Edition, 2009, Pearson.

REFERENCE BOOKS:

- 1. Horowitz -Electronic Devices and Circuits, David A. Bell -5thEdition, Oxford.
- 2. Chinmoy Saha, Arindam Halder, Debaati Ganguly Basic Electronics-Principles and Applications, Cambridge, 2018

MAPPING OF COURSE OUTCOMES (CO) WITH PO'S & PSO'S MATRIX:

Course	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12
CO1	3	1	2	-	-	1	1	-	-	-	-	1
CO2	3	2	3	-	-	2	1	-	-	-	-	1
CO3	3	3	3	-	-	2	1	-	-	-	-	1
CO4	3	3	3	-	-	2	1	-	-	-	-	1
CO5	3	3	3	-	-	2	1	-	-	-	-	1

	Course	Program Spe	<mark>cific</mark> Outcomes (P	SO's)	
	Outco	PSO1	PSO2	PSO3	
	mes				
	(CO's)				
	CO1	3	2		
	CO2	2	2		
our	CO3	ts to	Succ	cess	• •
	CO4	2	2		
	CO5	2	2		